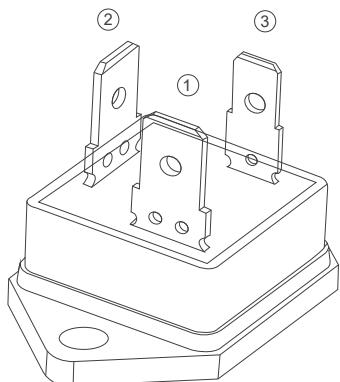


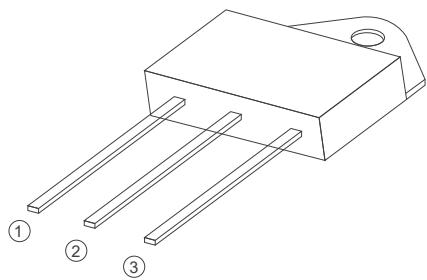
BTA41 Series  
40A TRIACs  
3 Quadrants  
4 Quadrants



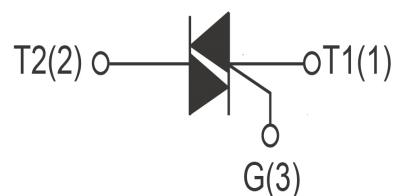
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TG-C



TO-3P Insulated



## FEATURES

- > IT(RMS): 40A
- > VGT: <1.5V
- > VDRM VRRM:800V~1600V

## APPLICATIONS

Washing machine, vacuums, massager, solid state relay, AC Motor speed regulation and so on.

**Absolute Maximum Ratings** ( $T_j=25^\circ\text{C}$  unless otherwise specified)

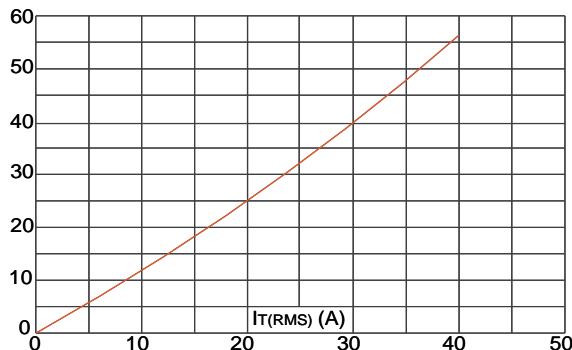
Symbol	Parameter	Conditions	Ratings	Unit
VDRM VRM	Repetitive Peak Off-State Voltage	BTA41-800B	800	V
		BTA41-1200B	1200	
		BTA41-1600B	1600	
IT(RMS)	R.M.S On-State Current	$T_c=110^\circ\text{C}$	40	A
ITSM	Surge On-State Current	$tp=16.7\text{ms}/tp=10\text{ms}$	400/420	
$I^2t$	$I^2t$ for fusing	$T_p=10\text{ms}$	520	$\text{A}^2\text{s}$
PG(AV)	Average Gate Power Dissipation	$T_j=125^\circ\text{C}$	1	W
IGM	Peak Gate Current	$T_j=125^\circ\text{C}$	8	A
$T_j$	Operating Junction Temperature		$\sim 40 \sim 125$	$^\circ\text{C}$
TSTG	Storage Temperature		$\sim 40 \sim 150$	

**Electrical Characteristics** ( $T_j=25^\circ\text{C}$  unless otherwise specified)

Symbol	Parameter	Test Conditions	BW	B	Unit
IDRM	Repetitive Peak Off-State Current	$T_j=25^\circ\text{C}$	5		uA
		$T_c=125^\circ\text{C}$	5		mA
IRRM	Repetitive Peak Reverse Current	$T_c=25^\circ\text{C}$	5		uA
		$T_c=125^\circ\text{C}$	5		mA
VTM	Forward "on" voltage	$IT=23\text{A}, tp=380\mu\text{s}$	1.55		V
VGT	Gate trigger voltage	$VD=12\text{V}, RL=30\Omega$		$\leq 1.5$	V
di/dt	$VD=2/3VDRM$ Gate Open, $T_j=125^\circ\text{C}$ I,II,III,IV	$F=100\text{Hz}, IG=2\times IGT, tr \leq 100\text{ns}$		50	A/us
IGT	Gate trigger current	$VD=12\text{V}, RL=30\Omega$	$\leq 50$	$\leq 50$	mA
			/	$\leq 100$	
IH	Holding current	$IT=0.2\text{A}$	$\leq 60$	$\leq 80$	
VGD	Gate non-trigger voltage	$VD=VDRM, TJ=125^\circ\text{C}, RL=3.3\text{K}\Omega$		0.2	V
dv/dt	Critical-rate of rise of commutation voltage	$TJ=125^\circ\text{C}, VD=2/3VDRM, Gate open circuit$	$\geq 1500$	$\geq 1000$	V/us

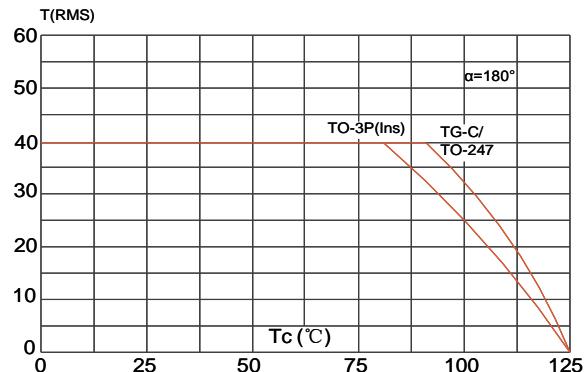
**FIG1**

Maximum power dissipation versus RMS on-state current



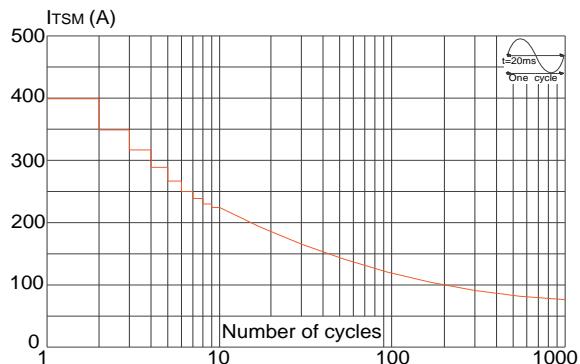
**FIG2**

RMS on-state current versus case temperature



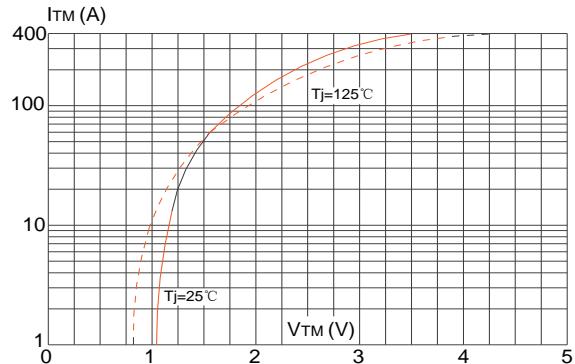
**FIG3**

Surge peak on-state current versus number of cycles



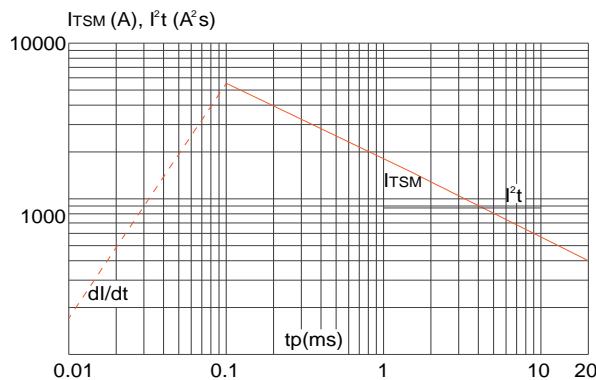
**FIG4**

On-state characteristics (maximum values)



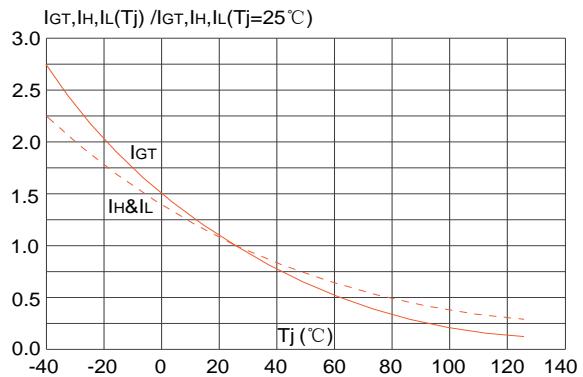
**FIG5**

Non-repetitive surge peak on-state current for a sinusoidal pulse with width  $tp < 20ms$ , and corresponding value of  $I^2t$  ( $dl/dt < 100A/\mu s$ )

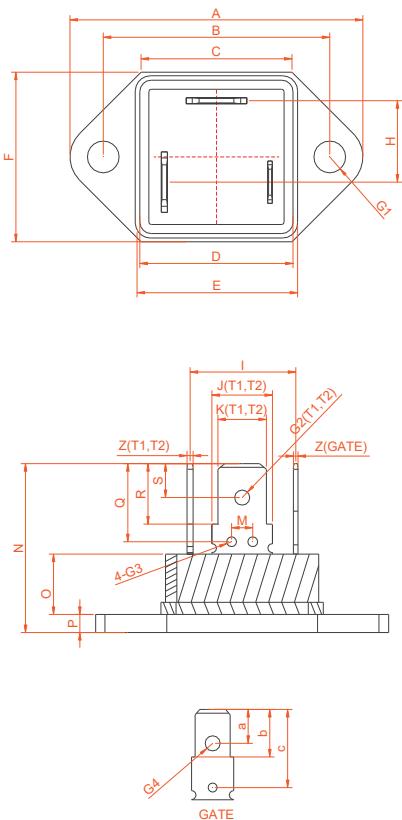


**FIG6**

**FIG.6:** Relative variations of gate trigger current, holding current and latching current versus junction temperature



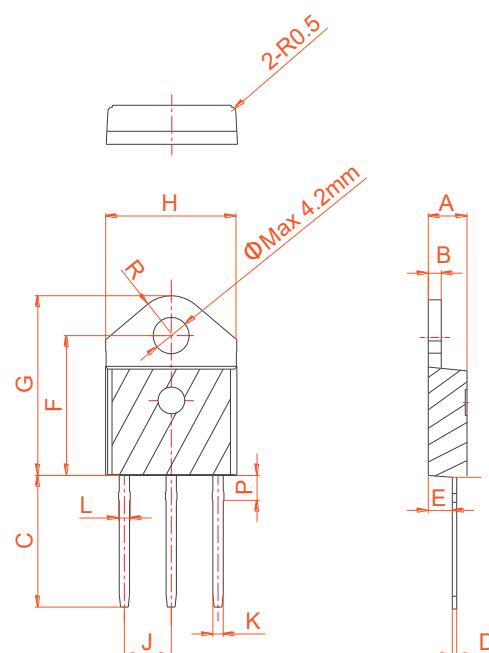
## PACKAGE MECHANICAL DATA



TG-C

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			39.2			1.543
B	29.8	30.0	30.2	1.173	1.181	1.189
C			21.6			0.85
D			20.2			0.795
E			20.5			0.791
F			23			0.906
T1、T2		8.10			0.318	
T3		5.65			0.222	
T'		6.35			0.25	
t1、t2		0.8			0.031	
t3		0.6			0.023	
G		13.9			0.547	
H1		2.6			0.102	
H2		10.8			0.425	
H			22.8			0.886
h1	6.2	6.35	6.5	0.244	0.25	0.256
h2	7.8	7.95	8.1	0.307	0.313	0.319
h3	9.45	9.75	10.05	0.372	0.384	0.396
I	2.7	3.0	3.3	0.106	0.118	0.130
J		10.8			0.425	

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.40		4.60	0.173		0.181
B	1.45		1.55	0.057		0.061
C	14.35		15.60	0.565		0.614
D	0.50		0.70	0.020		0.028
E	2.70		2.90	0.106		0.114
F	15.80		16.50	0.622		0.650
G	20.40		21.10	0.803		0.831
H	15.10		15.50	0.594		0.610
J	5.40		5.65	0.213		0.222
K	1.10		1.40	0.043		0.055
L	1.35		1.50	0.053		0.059
P	2.80		3.00	0.110		0.118
R		4.35		0.171		



TO-3P Ins



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